

# 2SC5353B

# NPN SILICON TRANSISTOR

# HIGH VOLTAGE NPN TRANSISTOR

## DESCRIPTION

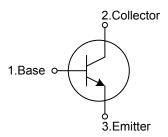
Switching Regulator and High Voltage Switching Applications High-Speed DC-DC Converter Applications.

### FEATURES

\* Excellent switching times:  $t_R = 0.7 \mu s_{(MAX)}$ ,  $t_F = 0.5 \mu s_{(MAX)}$ 

\* High collectors breakdown voltage:  $V_{CEO}$  = 750V

### SYMBOL



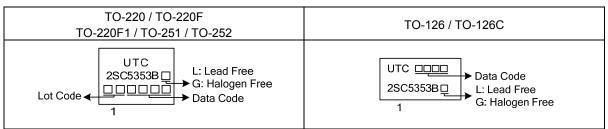
### ORDERING INFORMATION

1	1			
TO-126	TO-126C			
1	1			
TO-220	TO-220F			
1	1			
TO-220F1	TO-251			
1				
TO-252				

Ordering Number		Package	Pin Assignment			Deaking	
Lead Free	Lead Free Halogen Free		1	2	3	Packing	
2SC5353BL-T60-K	2SC5353BL-T60-K 2SC5353BG-T60-K		В	С	Е	Bulk	
2SC5353BL-T6C-K	2SC5353BL-T6C-K 2SC5353BG-T6C-K		В	С	Е	Bulk	
2SC5353BL-TA3-T 2SC5353BG-TA3-T		TO-220	В	С	Ш	Tube	
2SC5353BL-TF3-T	2SC5353BL-TF3-T 2SC5353BG-TF3-T		В	С	Ш	Tube	
2SC5353BL-TF1-T	2SC5353BL-TF1-T 2SC5353BG-TF1-T		В	С	Ш	Tube	
2SC5353BL-TM3-T	2SC5353BL-TM3-T 2SC5353BG-TM3-T		В	С	Ш	Tube	
2SC5353BL-TN3-R 2SC5353BG-TN3		TO-252	В	С	Е	Tape Reel	
Note: Pin Assignment: E: Emitter B: Base C: Collector							
2SC5353BL- <u>T60</u> -T	(1) K: Bulk, T: Tube, R: Tape Reel						
	— (1)Packing Type	(2) T60: TO-126, T6C: TO-126C, TA3: TO-220,					
	TF3: TO-220F, TM3: TO-251, TN3: TO-252						
	— (3)Green Package	TF1: TO-220F1					
	(-)	(3) L: Lead Free, G: Halogen Free and Lead Free					

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## MARKING





PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Base Voltage	ector-Base Voltage		900	V
Collector-Emitter Voltage		V <sub>CEO</sub>	750	V
Emitter-Base Voltage		V <sub>EBO</sub>	7	V
Collector Current	DC	lc	3	А
	Pulse	ulse I <sub>CP</sub> 5		А
Base Current		I <sub>B</sub>	1	
Power Dissipation	TO-126/TO-126C TO-220F/TO-220F1	5	20	W
	TO-220	P <sub>D</sub>	25	W
	TO-251/TO-252		22	W
Junction Temperature		T」 +150		°C
Storage Temperature		T <sub>STG</sub>	-40 ~ +150	°C

### ■ ABSOLUTE MAXIMUM RATINGS (T<sub>c</sub> = 25°C unless otherwise specified)

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

#### ELECTRICAL CHARACTERISTICS (T<sub>c</sub> = 25°C unless otherwise specified)

		i			i		i
PAF	RAMETER	SYMBOL	TEST CONDITIONS		TYP	MAX	UNIT
Collector-Base Breakdown Voltage		<b>BV</b> <sub>CBO</sub>	I <sub>C</sub> =1 mA, I <sub>E</sub> = 0	900			V
Collector-Emitte	r Breakdown Voltage	BV <sub>CEO</sub>	I <sub>C</sub> =10 mA, I <sub>B</sub> = 0	750			V
Collector Cut-off	Current	I <sub>CBO</sub>	V <sub>CB</sub> =720V, I <sub>E</sub> = 0			100	μA
Emitter Cut-off C	Current	I <sub>EBO</sub>	V <sub>EB</sub> =7V, I <sub>C</sub> = 0			10	μA
DC Current Gain		h <sub>FE1</sub>	V <sub>CE</sub> =5 V, I <sub>C</sub> =1 mA V <sub>CE</sub> =5 V, I <sub>C</sub> =0.15 A				
		h <sub>FE2</sub>					
Collector-Emitte	r Saturation Voltage	V <sub>CE(SAT)</sub>	I <sub>C</sub> =1.2 A, I <sub>B</sub> =0.24 A			1.0	V
Base-Emitter Sa	turation Voltage	V <sub>BE(SAT)</sub>	I <sub>C</sub> =1.2 A, I <sub>B</sub> =0.24 A			1.3	V
Switching Time	Rise Time	t <sub>R</sub>	Output Ic ↓≶ 88 20µS			0.7	μS
	Storage Time	t <sub>stg</sub>				4.0	μS
	Fall Time	t⊧	V <sub>CC</sub> ≈360V I <sub>B1</sub> = 0.24 A, I <sub>B2</sub> = −0.48 A, duty cycle ≤ 1%			0.5	μS

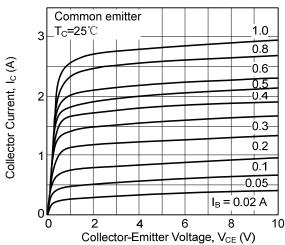


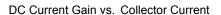
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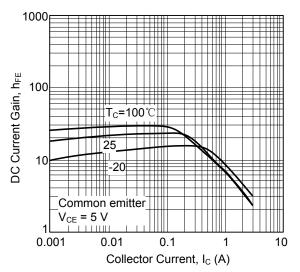
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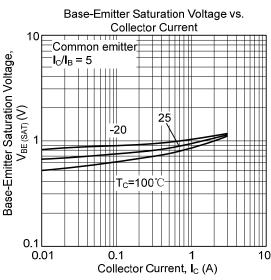
### **TYPICAL CHARACTERISTICS**

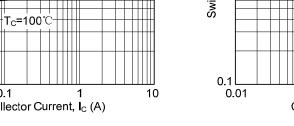
Collector Current vs. Collector-Emitter Voltage



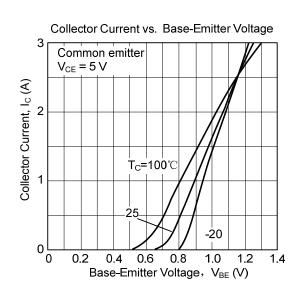


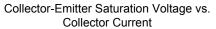


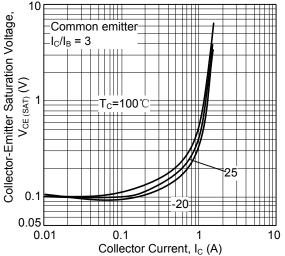


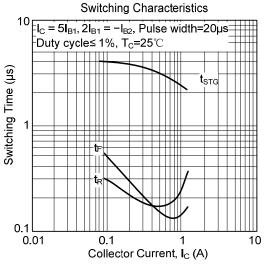




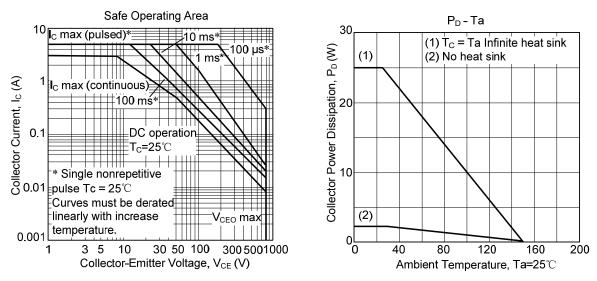












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